Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-985-1874

### Inclosure Material:

Metal

### **Overall Length:**

Between 0.250 inches and 0.450 inches

## **Overall Diameter:**

0.875 inches

### **Mounting Facility Quantity:**

## 2

# Electrode Internally-electrically Connected To Case:

Cathode

# Mounting Method:

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

51.0 regulator voltage

#### **Current Rating Per Characteristic:**

245.00 milliamperes repetitive peak forward current

## Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 pin

#### **Specification Data:**

81349-mil-s-19500/114 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

--

## Demilitarization:

No

Fiig:

A110a0

## Mil-std (military Standard):

Mil-prf-19500 spec.